FAIRCHILD

SEMICONDUCTOR

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MM88C29 • MM88C30 **Quad Single-Ended Line Driver • Dual Differential Line Driver**

General Description

The MM88C30 is a dual differential line driver that also performs the dual four-input NAND or dual four-input AND function. The absence of a clamp diode to $V_{\mbox{\scriptsize CC}}$ in the input protection circuitry of the MM88C30 allows a CMOS user to interface systems operating at different voltage levels. Thus, a CMOS digital signal source can operate at a $V_{\rm CC}$ voltage greater than the V_{CC} voltage of the MM88C30 line driver. The differential output of the MM88C30 eliminates ground-loop errors.

The MM88C29 is a non-inverting single-wire transmission line driver. Since the output ON resistance is a low 20Ω typ., the device can be used to drive lamps, relays, solenoids, and clock lines, besides driving data lines.

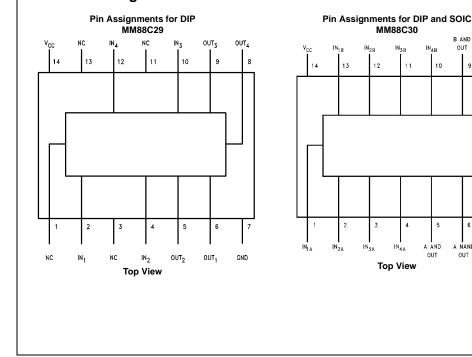
Features

- Wide supply voltage range: 3V to 15V
- High noise immunity: 0.45 V_{CC} (typ.)
- Low output ON resistance: 20Ω (typ.)

Ordering Code:

Order Number	Package Number	Package Description		
MM88C29N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide		
MM88C30M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow		
MM88C30N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide		
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.				

Connection Diagrams



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B NAND

OUT

8

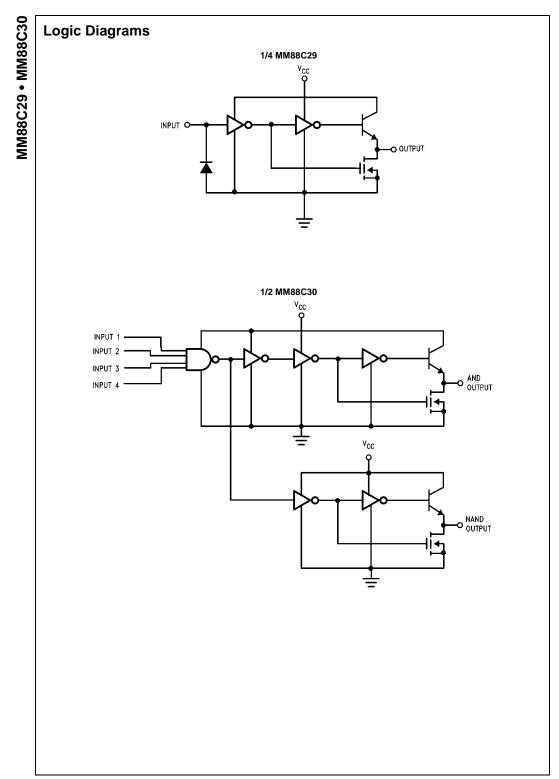
B AND

OUT

A NAND

OUT

9



Absolute Maximum Ratings(Note 1)

Voltage at Any Pin (Note 2) Operating Temperature Range	–0.3V to V _{CC} +16V –40°C to +85°C
Storage Temperature	-65°C to +150°C
Power Dissipation (P _D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V _{CC} Range	3V to 15V
Absolute Maximum V_{CC}	18V

Average Current at Output			
MM88C30	50 mA		
MM88C29	25 mA		
Maximum Junction Temperature, Tj	150°C		
Lead Temperature			
(Soldering, 10 seconds)	260°C		

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions for actual device operation.

Note 2: AC Parameters are guaranteed by DC correlated testing.

DC Electrical Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Units
смоѕ то	CMOS			11		
V _{IN(1)}	Logical "1" Input Voltage	$V_{CC} = 5V$	3.5			V
.,		$V_{CC} = 10V$	8			V
V _{IN(0)}	Logical "0" Input Voltage	$V_{CC} = 5V$			1.5	V
.,		$V_{CC} = 10V$			2	V
I _{IN(1)}	Logical "1" Input Current	V _{CC} = 15V, V _{IN} = 15V		0.005	1	μΑ
I _{IN(0)}	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1	-0.005		μΑ
Icc	Supply Current	$V_{CC} = 5V$		0.05	100	mA
Ουτρυτ Ι	DRIVE		•			
ISOURCE	Output Source Current	$V_{OUT} = V_{CC} - 1.6V,$				
		$V_{CC} \ge 4.75 V$, $T_j = 25^{\circ}C$	-47	-80		mA
		T _i = 85°C	-32	-60		mA
	MM88C29	$V_{OUT} = V_{CC} - 0.8V$	-2	-20		mA
	MM88C30	$V_{CC} \ge 4.5V$				
I _{SINK}	Output Sink Current	$V_{OUT} = 0.4V, V_{CC} = 4.75V,$				
		$T_i = 25^{\circ}C$	9.5	22		mA
		T _i = 85°C	8	18		mA
		$V_{OUT} = 0.4V, V_{CC} = 10V,$				
		$T_i = 25^{\circ}C$	19	40		mA
		T _i = 125°C	15.5	33		mA
ISOURCE	Output Source Resistance	$V_{OUT} = V_{CC} - 1.6V,$				
		$V_{CC} \ge 4.75$ V, $T_j = 25^{\circ}$ C		20	34	Ω
		$T_j = 85^{\circ}C$		27	50	Ω
I _{SINK}	Output Sink Resistance	V _{OUT} = 0.4V, V _{CC} = 4.75V,				
		$T_j = 25^{\circ}C$		18	41	Ω
		$T_j = 85^{\circ}C$		22	50	Ω
		$V_{OUT} = 0.4V, V_{CC} = 10V,$				
		$T_j = 25^{\circ}C$		10	21	Ω
		$T_j = 85^{\circ}C$		12	26	Ω
	Output Resistance					
	Temperature Coefficient					
	Source			0.55		%/°C
	Sink			0.40		%/°C
θ _{JA}	Thermal Resistance			150		°C/W
	(N-Package)					

MM88C29 • MM88C30

Symbol	Parameter	Conditions	Min	Тур	Max	Un
t _{pd}	Propagation Delay Time to					
	Logical "1" or "0"	(See Figure 1)				
	MM88C29	$V_{CC} = 5V$		80	200	n
		$V_{CC} = 10V$		35	100	r
	MM88C30	$V_{CC} = 5V$		110	350	n
		$V_{CC} = 10V$		50	150	n
t _{pd}	Differential Propagation Delay	$R_L = 100\Omega, \ C_L = 5000 \ pF$				
	Time to Logical "1" or "0"	(See Figure 2)				
	MM88C30	$V_{CC} = 5V$			400	n
		$V_{CC} = 10V$			150	n
C _{IN}	Input Capacitance					
	MM88C29	(Note 3)		5.0		р
	MM88C30	(Note 3)		5.0		р
C _{PD}	Power Dissipation Capacitance					
	MM88C29	(Note 3)		150		р
	MM88C30	(Note 3)		200		р

Note 3: Capacitance is guaranteed by periodic testing. Note 4: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics application note AN-90 (CMOS Logic Databook).

-**O** OUTPUT



